



S E M I C O N D U C T O R

1N5817 THRU 1N5819

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage 20 to 40 Volts

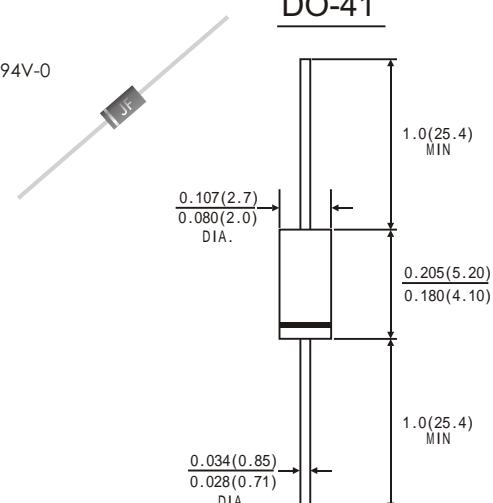
Forward Current - 1.0Ampere

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:250 C/10 seconds at terminals, 0.375"(9.5mm)lead length,5lbs.(2.3kg)tension

MECHANICAL DATA

- Case: JEDEC DO-41 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.01ounce, 0.33 gram



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	1N5817	1N5818	1N5819	Units	
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	Volts	
Maximum RMS voltage	V _{RMS}	14	21	28	Volts	
Maximum DC blocking voltage	V _{DC}	20	30	40	Volts	
Maximum non-repetitive peak reverse voltage	V _{RSM}	24	36	48	Volts	
Maximum average forward rectified current 0.375"(9.5mm)lead length at T _L =90°C	I _(AV)	1.0			Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method) at T _L =70°C	I _{FSM}	25.0			Amps	
Maximum instantaneous forward voltage at 1.0 A(note 1)	V _F	0.450	0.550	0.600	Volts	
Maximum instantaneous forward voltage at 3.1 A(note 1)	V _F	0.750	0.875	0.900	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	0.5			mA	
T _A =25°C		10.0				
T _A =100°C						
Typical junction capacitance(Note 3)	C _J	110.0			pF	
Typical thermal resistance(Note 2)	R _{θ JA} R _{θ JL}	50.0 15.0			°C/W	
Operating junction and storage temperature range	T _{J TstG}	-65 to +125			°C	

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance (from junction to ambient)Vertical P.C.B. mounted , with 1.5X1.5"(38X38mm)copper pads

3.Measured at 1.0MHz and reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES 1N5817 THRU 1N5819

FIG.1-FORWARD CURRENT DERATING CURVE

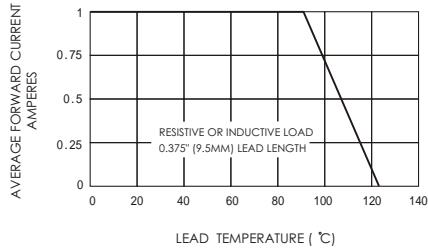


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

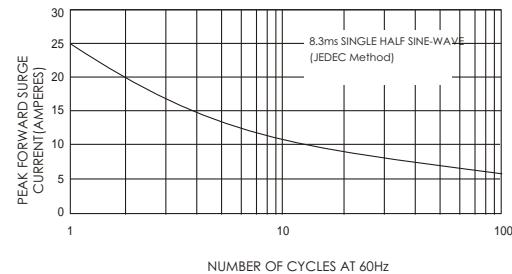


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

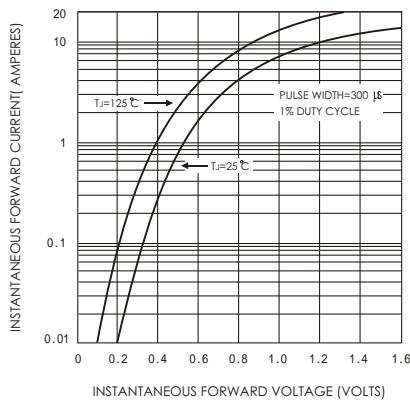


FIG.4-TYPICAL REVERSE CHARACTERISTICS

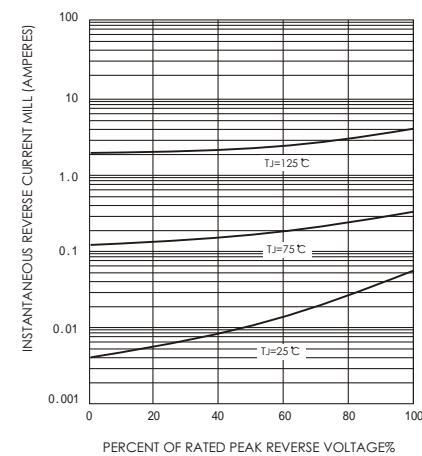


FIG.5-TYPICAL JUNCTION CAPACITANCE

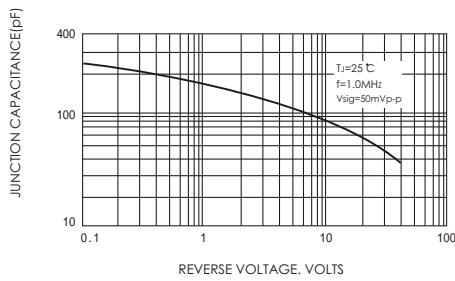


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

